

# FG6000AU-120D

HIGH POWER INVERTER USE  
PRESS PACK TYPE

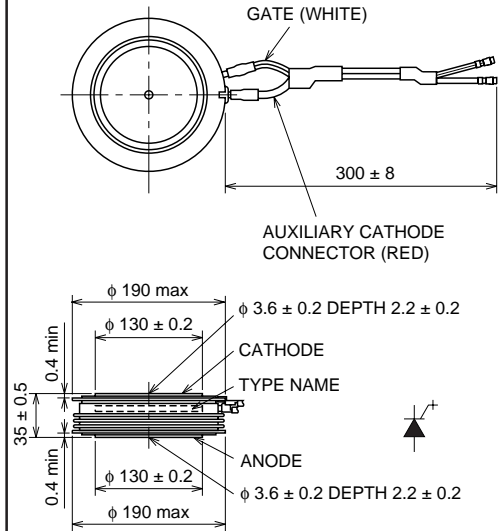
## FG6000AU-120D



- ITQRM Repetitive controllable on-state current ..... 6000A
- IT(AV) Average on-state current ..... 1500A
- QRR Repetitive peak off state voltage ..... 6000V
- Anode short type

## OUTLINE DRAWING

Dimension in mm



## APPLICATION

Inverters, Converters, DC choppers, Induction heating, DC to DC converters.

## MAXIMUM RATINGS

Symbol	Parameter	Voltage class		Unit
		120D		
VRRM	Repetitive peak reverse voltage	22		V
VRSM	Non-repetitive peak reverse voltage	22		V
VR(DC)	DC reverse voltage	22		V
VDRM	Repetitive peak off-state voltage <sup>+</sup>	6000		V
VDSM	Non-repetitive peak off-state voltage <sup>+</sup>	6000		V
VD(DC)	DC off-state voltage <sup>+</sup>	4800		V

<sup>+</sup> : V<sub>GK</sub> = -2V

Symbol	Parameter	Conditions	Ratings	Unit
ITQRM	Repetitive controllable on-state current	V <sub>D</sub> = 3000V, V <sub>DM</sub> = 5500V, T <sub>j</sub> = 125°C, C <sub>s</sub> = 6.0μF, L <sub>s</sub> = 0.2μH	6000	A
IT(RMS)	RMS on-state current		3100	A
IT(AV)	Average on-state current	f = 60Hz, sine wave θ = 180°, T <sub>f</sub> = 72°C	2000	A
ITSM	Surge (non-repetitive) on-state current	One half cycle at 60Hz	40	kA
I <sup>2</sup> t	Current-squared, time integration	One cycle at 60Hz	6.7 × 10 <sup>6</sup>	A <sup>2</sup> s
diT/dt	Critical rate of rise of on-state current	V <sub>D</sub> = 3000V, I <sub>GM</sub> = 90A, T <sub>j</sub> = 125°C	500	A/μs
VFGM	Peak forward gate voltage		10	V
VRGM	Peak reverse gate voltage		22	V
IFGM	Peak forward gate current		200	A
IRGM	Peak gate reverse current		2400	A
PFGM	Peak forward gate power dissipation		2000	W
PRGM	Peak reverse gate power dissipation		50	kW
PFG(AV)	Average forward gate power dissipation		140	W
PRG(AV)	Average reverse gate power dissipation		630	W
T <sub>j</sub>	Junction temperature		-40 ~ +125	°C
T <sub>stg</sub>	Storage temperature		-40 ~ +150	°C
—	Mounting force required	Recommended value 108	98 ~ 118	kN
—	Weight	Standard value	4600	g

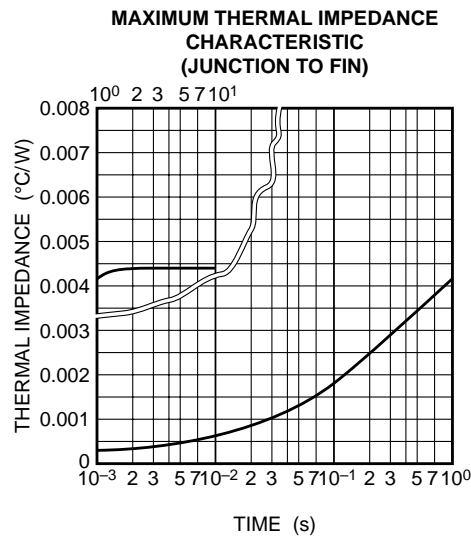
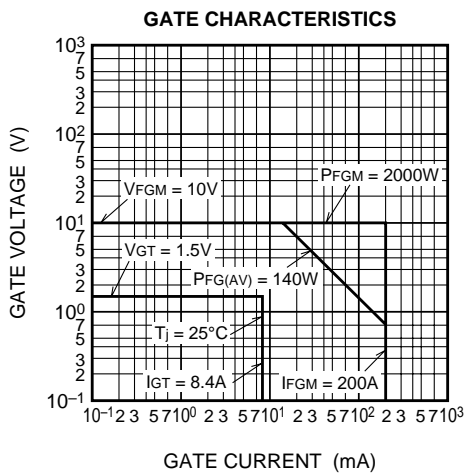
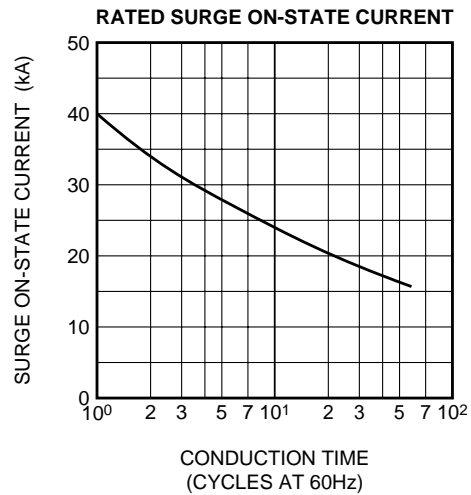
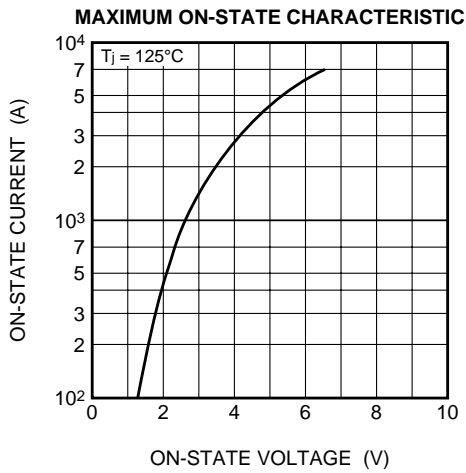
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## ELECTRICAL CHARACTERISTICS

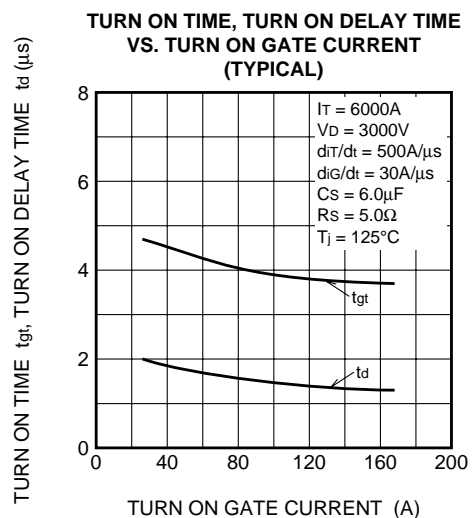
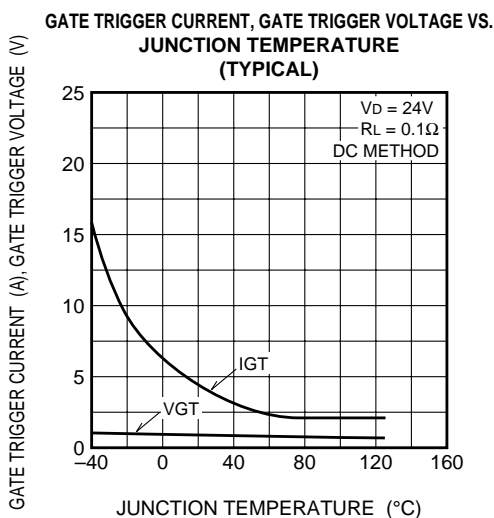
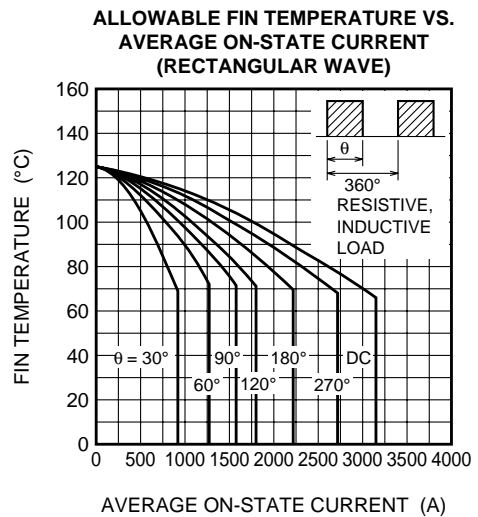
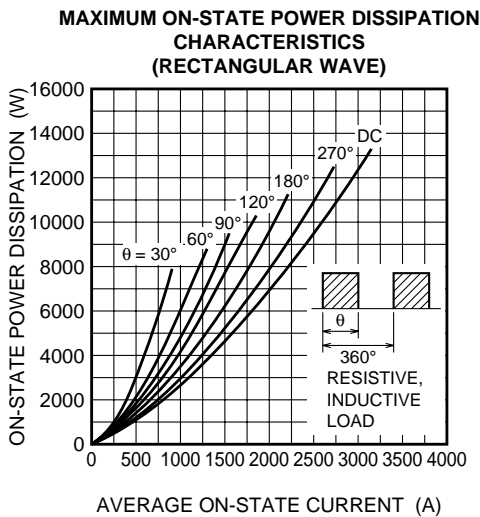
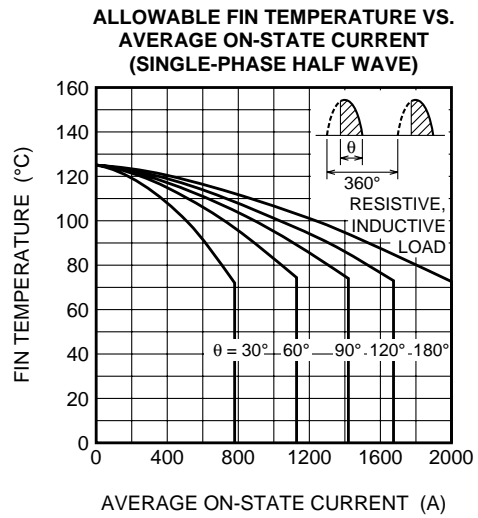
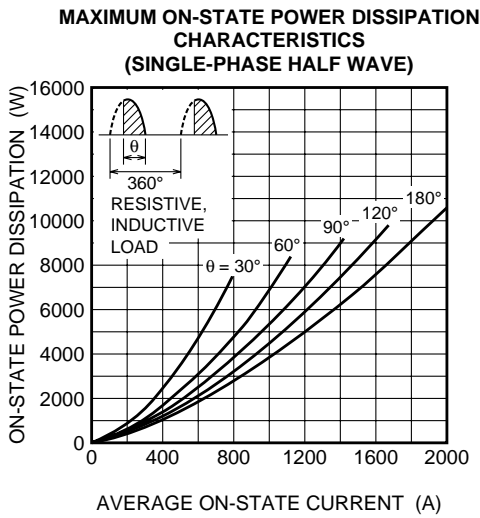
Symbol	Parameter	Test conditions	Limits			Unit
			Min	Typ	Max	
V <sub>TM</sub>	On-state voltage	T <sub>j</sub> = 125°C, I <sub>TM</sub> = 6000A, Instantaneous measurement	—	—	6.0	V
I <sub>RRM</sub>	Repetitive peak reverse current	T <sub>j</sub> = 125°C, V <sub>RRM</sub> Applied	—	—	100	mA
I <sub>DRM</sub>	Repetitive peak off-state current	T <sub>j</sub> = 125°C, V <sub>DRM</sub> Applied, V <sub>GK</sub> = -2V	—	—	320	mA
I <sub>RG</sub>	Reverse gate current	T <sub>j</sub> = 125°C, V <sub>RG</sub> = 22V	—	—	100	mA
dv/dt	Critical rate of rise of off-state voltage	T <sub>j</sub> = 125°C, V <sub>D</sub> = 3000V, V <sub>DM</sub> = 5500V, V <sub>GK</sub> = -2V	1000	—	—	V/μs
t <sub>gt</sub>	Turn-on time	T <sub>j</sub> = 125°C, I <sub>TM</sub> = 6000A, I <sub>GM</sub> = 90A, V <sub>D</sub> = 3000V	—	—	10	μs
t <sub>gq</sub>	Turn-off time	T <sub>j</sub> = 125°C, I <sub>TM</sub> = 6000A, V <sub>DM</sub> = 5500V, di <sub>GQ</sub> /dt = -80A/μs V <sub>RG</sub> = 20V, C <sub>S</sub> = 6.0μF, L <sub>S</sub> = 0.2μH	—	—	30	μs
I <sub>GQM</sub>	Peak gate turn-off current		—	1800	—	A
V <sub>GT</sub>	Gate trigger voltage	DC METHOD : V <sub>D</sub> = 24V, R <sub>L</sub> = 0.1Ω, T <sub>j</sub> = 25°C	—	—	1.5	V
I <sub>GT</sub>	Gate trigger current		—	—	8.4	A
R <sub>th(j-f)</sub>	Thermal resistance	Junction to fin	—	—	0.0044	°C/W

## PERFORMANCE CURVES



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